PECVD, PRECURSORS AND SURCOTEC KNOW-HOW

Surcotec has built its reputation in the vacuum metallization industry and since 2006, SURCOTEC is a leader in PECVD technology.

Thanks to our know-how and innovations we produce high quality films.

Plasma Enhanced Chemical Vapor Deposition (PECVD) is a process by which thin films of various materials can be deposited on substrates at **lower temperature** than the standard Chemical Vapor Deposition (CVD).

In PECVD processes, deposition is achieved by introducing reactant gases between two electrodes, a grounded electrode and an RF-energized electrode. The capacitive coupling between the electrodes excites the reactant gases into a plasma, which induces a chemical reaction and results in the reaction product being deposited on the substrate. The lower deposition temperatures are critical in many applications where CVD temperatures could damage the devices being manufactured.

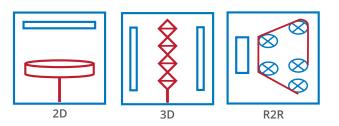
APPLICATIONS

Carbon (C)	Barrier coating ; Black coating		
Silicon Oxide (SiOx)	Barrier coating, Optical filter, anti-finger print		These encap
Silicon nitride (SixNy)	Barrier coating, Optical filter, anti-finger print		from
Silicon oxy carbide (SiOxCy)	Low friction		eleme oxyge
Titanium Oxide (TiO2)	Antimicrobic, Optical filter		

These films are also used for encapsulation to protect devices from corrosion by atmospheric elements such as moisture and oxygen.

PECVD GEOMETRY VARIANTS

TYPICAL FORMULATION AND APPLICATION USED AT SURCOTEC



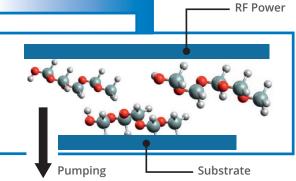
OTHER APPLICATION

ALD (AI203)

Barrier coating for watch industry



Inert gas, process gas precursor





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